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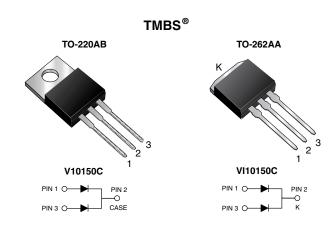


V10150C, VI10150C

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.63$ V at $I_F = 3$ A



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 5.0 A				
V _{RRM}	150 V				
I _{FSM}	60 A				
V _F at I _F = 5 A	0.69 V				
T _J max.	150 °C				

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads. solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test. HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER		SYMBOL	V10150C	VI10150C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	150		V	
Maximum average forward rectified current (fig. 1)	per device	1	10		A	
	per diode	I _{F(AV)}	5.0			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	60		А	
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	- 55 to	+ 150	°C	

RoHS COMPLIANT HALOGEN FREE

Revision: 23-Mar-11

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 3 A	T _A = 25 °C	- V _F (1)	0.82	-	V	
	I _F = 5 A			0.99	1.41		
	I _F = 3 A	- T _A = 125 °C		0.63	-		
	I _F = 5 A			0.69	0.75		
Reverse current per diode	V _R = 100 V	T _A = 25 °C	I _R ⁽²⁾	0.5	-	μA	
		T _A = 125 °C		0.5	-	mA	
	V _P = 150 V	T _A = 25 °C		_	100	μA	
		T _A = 125 °C		1.0	10	mA	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	L V10150C VI10150C		UNIT	
Typical thermal resistance per diode	$R_{ extsf{ heta}JC}$	4.0		°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V10150C-M3/4W	1.87	4W	50/tube	Tube		
TO-262AA	VI10150C-M3/4W	1.45	4W	50/tube	Tube		
TO-220AB	V10150CHM3/4W (1)	1.87	4W	50/tube	Tube		
TO-262AA	VI10150CHM3/4W ⁽¹⁾	1.45	4W	50/tube	Tube		

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

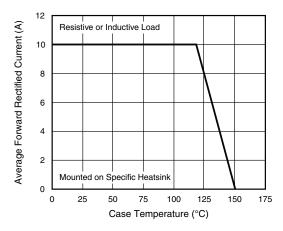


Fig. 1 - Maximum Forward Current Derating Curve

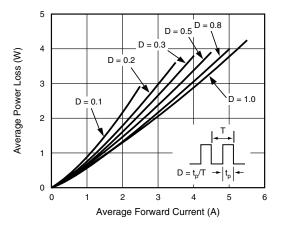


Fig. 2 - Forward Power Loss Characteristics Per Diode

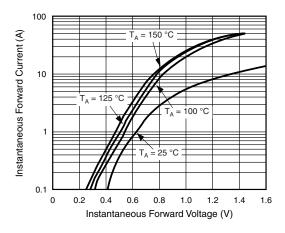


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

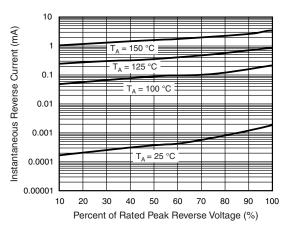


Fig. 4 - Typical Reverse Characteristics Per Diode

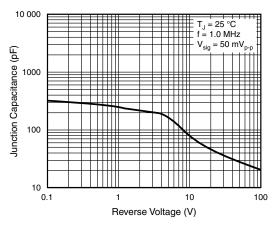
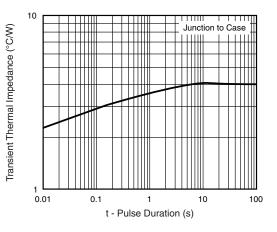
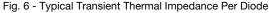


Fig. 5 - Typical Junction Capacitance Per Diode





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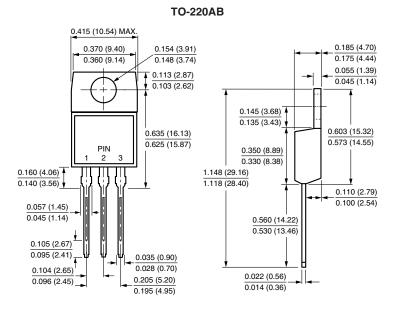
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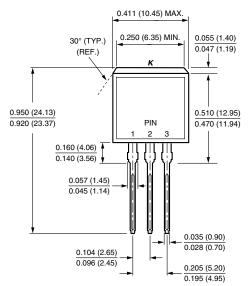
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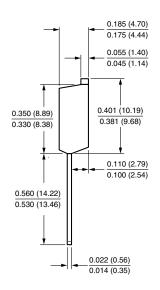
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-262AA







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